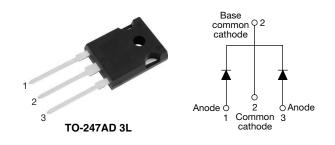
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Hyperfast Rectifier, 2 x 30 A FRED Pt[®] G5



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I _{F(AV)} , per leg	30 A						
V _R	600 V						
V _F at I _F at 125 °C, per leg	1.15 V						
t _{rr} (typ.)	25						
I _{FSM} , per leg	330						
T _J max.	175 °C						
Package	TO-247AD 3L						
Circuit configuration	Common cathode						

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 3L Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage, per leg	V _{RRM}		600	V					
Average rectified forward current, per leg	I _{F(AV)}	T _C = 123 °C, D = 0.50	30						
Non-repetitive peak surge current, per leg	I _{FSM}	$T_C = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	330	А					
Repetitive peak forward current, per leg	I _{FRM}	T _C = 123 °C, D = 0.50, f = 20 kHz	60						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage, per leg	V_{BR}, V_{R}	I _R = 100 μA	600	-	-				
Forward voltage, per leg	V _F	I _F = 30 A	-	1.3	1.6	V			
		I _F = 30 A, T _J = 125 °C	-	1.15	-				
	I _R	V _R = V _R rated	-	-	20				
Reverse leakage current, per leg		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA			
Junction capacitance, per leg	CT	V _R = 200 V	-	36	-	pF			
Series inductance, per leg	L _S	Measured to lead 5 mm from package body	-	8	-	nH			

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_{\rm F} = 1.0 \rm A, dI_{\rm F}/c$	t = 100 A/µs, V _R = 30 V	-	25	-		
Reverse recovery time, per leg	t _{rr}	$T_J = 25 \ ^\circ C$		-	41	-	ns	
		T _J = 125 °C		-	58	-		
Poole recovery ourrent per leg	1	T _J = 25 °C	$I_F = 20 \text{ A},$	-	19	-	A	
Peak recovery current, per leg	I _{RRM}	T _J = 125 °C	dI _F /dt = 1000 A/μs, V _R = 400 V	-	32	-		
Reverse recovery charge, per leg	Q _{rr}	T _J = 25 °C		-	419	-	nC	
neverse recovery charge, per leg		T _J = 125 °C		-	1176	-		
Poverse receiver time, per leg	+	$T_J = 25 \ ^\circ C$	I _F = 30 A, dI _F /dt = 1000 A/μs, V _B = 400 V	-	46	-	20	
Reverse recovery time, per leg	t _{rr}	T _J = 125 °C		-	65	-	ns	
Deale recovery ourrent per les		T _J = 25 °C		-	21	-	A	
Peak recovery current, per leg	I _{RRM}	T _J = 125 °C		-	36	-		
		T _J = 25 °C		-	550	-	-	
Reverse recovery charge, per leg	Q _{rr}	T _J = 125 °C		-	1560	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction-to-case, per leg	R _{thJC}		-	-	1.1	°C/W			
Weight			-	5.5	-	g			
			-	0.2	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C			
Marking device		Case style: TO-247AD 3L	C5PH6006L						

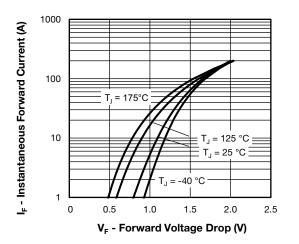


Fig. 1 - Forward Voltage Drop Characteristics, per Leg

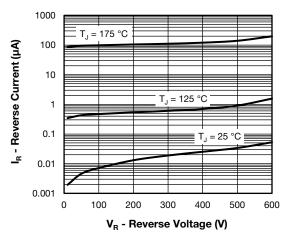
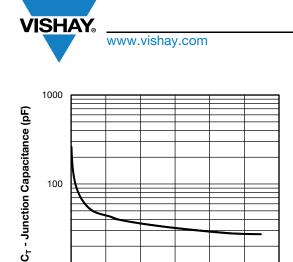


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, per Leg



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10

0

100

200

300 V_R - Reverse Voltage (V)

400

500

600

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, per Leg

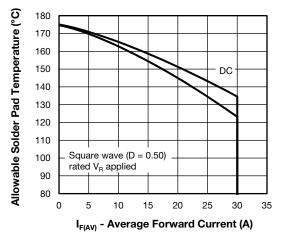


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, per Leg

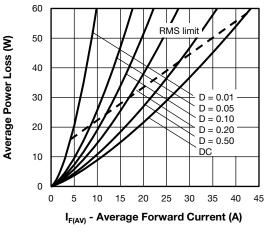


Fig. 5 - Forward Power Loss Characteristics, per Leg

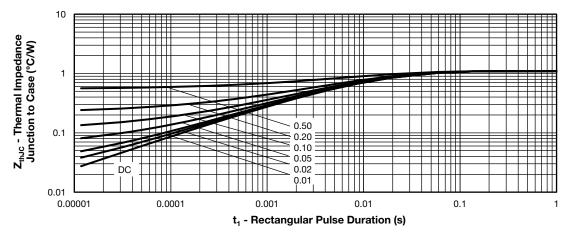


Fig. 6 - Transient Thermal Impedance, Junction to Case, per Leg

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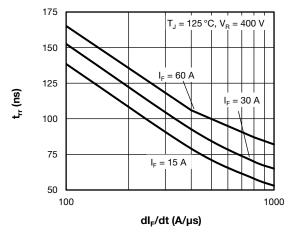


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt, per Leg

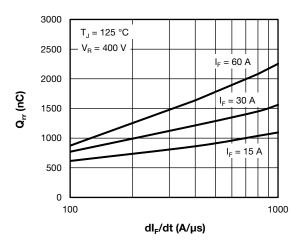


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, per Leg

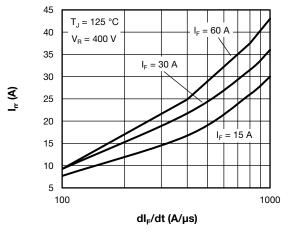
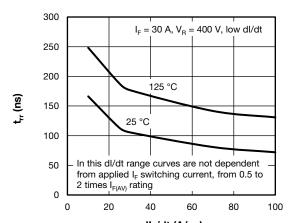


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt, per Leg



dI_F/dt (A/µs)

Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt, per Leg

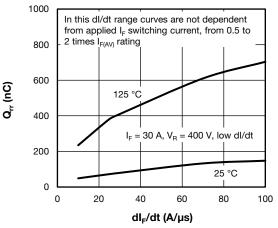


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt, per Leg

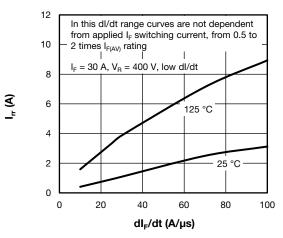


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt, per Leg

VS-C5PH6006L-N3

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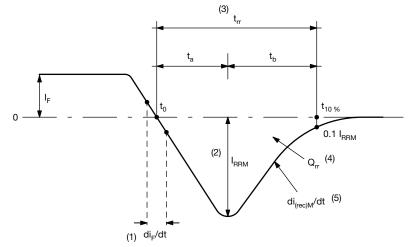


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- ⁽¹⁾ di_F/dt rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$ peak reverse recovery current
- ⁽³⁾ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM} ⁽⁴⁾ Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_0\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	с	5	Р	н	60	06	L	-N3
	1	2	3	4	5	6	7	8	9
	1 -	· Visl	nay Sem	nicondu	ctors pro	oduct			
	2 -			figuratio on catho					
	3 -	- FRED Pt [®] Gen 5							
	4 -	- P=	TO-247	7 packag	ge				
	5		cess typ hyperfa	oe: ast reco	very				
	6 -			ing (60 =	-				
	7 -	- Voltage rating $(06 = 600 \text{ V})$							
	8 -	Pac	kage: L	= long	lead (TC)-247A[D)		
	9 -			ntal digit gen-free		-compli	ant, and	d totally	lead (Pt

ORDERING INFORMATION (Example)								
PREFERRED P/N	REFERRED P/N QUANTITY PER TUBE BASE QUANTITY PACKAGING DESCRIPTION							
VS-C5PH6006L-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS								
Dimensions www.vishay.com/doc?95626								
Part marking information www.vishay.com/doc?95007								
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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.209 A 4.65 5.31 0.183 0.087 0.102 A1 2.21 2.59 1.50 2.49 0.059 0.098 A2 b 0.99 1.40 0.039 0.055 b1 0.99 1.35 0.039 0.053 b2 1.65 2.39 0.065 0.094 b3 1.65 2.34 0.065 0.092 b4 2.59 3.43 0.102 0.135 b5 2.59 3.38 0.102 0.133 с 0.38 0.89 0.015 0.035 c1 0.38 0.84 0.015 0.033 D 19.71 20.70 0.776 0.815 3 D1 13.08 -0.515 4

(4) Section C - C, D - D, E - E

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.30	0.020	0.051		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØК	0.2	0.254		0.010		
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51	BSC	0.217	BSC		

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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